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BIBDATASHEET

CONFIRMATION NO. 3218

Bib Data Sheet

SERIAL NUMBER 10/714,829	FILING DATE 11/14/2003 RULE	CLASS 438	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. 81784.0291
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APPLICANTS

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** CONTINUING DATA ^{YES} _m

This application is a CON of 09/291,538 04/14/1999 ABN, which is a Div of 08/911,505
 Pat No. 6,274,414.

** FOREIGN APPLICATIONS ^{YES} _m

JAPAN HEI 8-217424 08/19/1996

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 02/23/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 25	TOTAL CLAIMS 5	INDEPENDENT CLAIMS 1
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance _m	Verified and Acknowledged	Examiner's Signature _m	Initials	

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TITLE
 Laser anneal method of a semiconductor layer

☐ All Fees